Diode Semiconductor Device - Page 1 of 1



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Incl	losure Material:
Gla	ss and metal
Ove	erall Length:
2.25	50 inches
Ove	erall Diameter:
1.2	18 inches
Мо	unting Facility Quantity:
1	
Joi	nt Electronic Device Engineering Council/jedec/case Outline Designation:
Do-	9
Мо	unting Method:
Thr	eaded stud
Fea	atures Provided:
Her	metically sealed case
Thr	read Size:
0.75	50 inches
Ser	niconductor Material:
Silio	con
Vol	tage Rating In Volts Per Characteristic:
600	0.0 reverse voltage, peak
Cur	rrent Rating Per Characteristic:
275	5.00 amperes forward current, average absolute
Max	ximum Operating Tempurature Per Measurement Point:
190	0.0 degrees celsius junction
Thr	read Series Designator:
Unf	
Ter	minal Type And Quantity:
1 th	readed stud and 1 uninsulated wire lead w/terminal lug
Spe	ecification Data:
801	31-release4215 professional/industrial association specification
She	elf Life:
N/a	
Uni	it Of Measure:
Der	nilitarization:
No	
Fiig	j:
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